

2SB1375

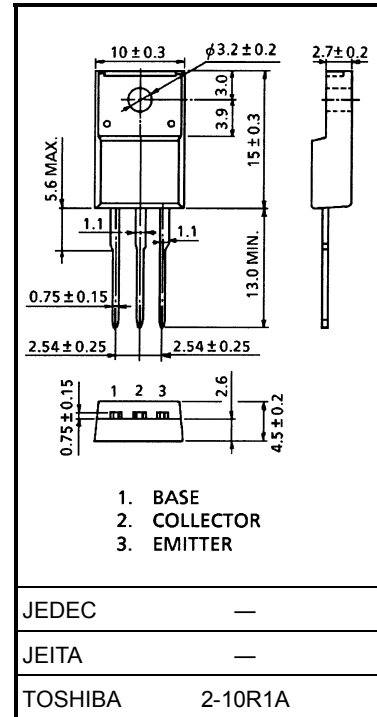
Audio Frequency Power Amplifier

Unit: mm

- Low saturation voltage: $V_{CE(sat)} = -1.5 \text{ V (max)}$
($I_C = -2 \text{ A}, I_B = -0.2 \text{ A}$)
- High power dissipation: $P_C = 25 \text{ W (} T_c = 25^\circ\text{C)}$
- Collector metal (fin) is covered with mold resin
- Complementary to 2SD2012

Maximum Ratings ($T_c = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	-60	V
Collector-emitter voltage		V_{CEO}	-60	V
Emitter-base voltage		V_{EBO}	-7	V
Collector current		I_C	-3	A
Base current		I_B	-0.5	A
Collector power dissipation	$T_a = 25^\circ\text{C}$	P_C	2.0	W
	$T_c = 25^\circ\text{C}$		25	
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$



Weight: 1.7 g (typ.)

Electrical Characteristics ($T_c = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = -60 \text{ V}, I_E = 0$	—	—	-10	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -7 \text{ V}, I_C = 0$	—	—	-10	μA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -50 \text{ mA}, I_B = 0$	-60	—	—	V
DC current gain	$h_{FE(1)}$	$V_{CE} = -5 \text{ V}, I_C = -0.5 \text{ A}$	100	—	320	
	$h_{FE(2)}$	$V_{CE} = -5 \text{ V}, I_C = -2 \text{ A}$	15	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -2 \text{ A}, I_B = -0.2 \text{ A}$	—	-1.0	-1.5	V
Base-emitter voltage	V_{BE}	$V_{CE} = -5 \text{ V}, I_C = -0.5 \text{ A}$	—	-0.75	-1.0	V
Transition frequency	f_T	$V_{CE} = -5 \text{ V}, I_C = -0.5 \text{ A}$	—	9	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	—	50	—	pF

Marking

